MAC12 SERIES*

***Motorola preferred devices**

Advance Information

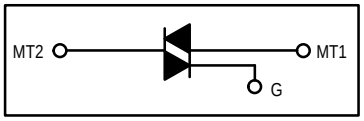
TRIACS

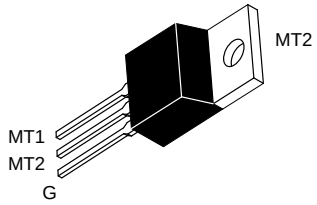
Silicon Bidirectional Thyristors

TRIACS
12 AMPERES RMS
400 thru 800
VOLTS

Designed for high performance full–wave ac control applications where high noise immunity and commutating di/dt are required.

- Blocking Voltage to 800 Volts
- On–State Current Rating of 12 Amperes RMS at 70°C
- Uniform Gate Trigger currents in Three Modes
- High Immunity to dv/dt — 250 V/µs minimum at 125°C
- High Commutating di/dt — 6.5 A/ms minimum at 125°C
- Industry Standard TO–220 AB Package
- High Surge Current Capability — 120 Amperes





CASE 221A-09
(TO-220AB)
Style 4

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Parameter		Symbol	Value	Unit
Peak Repetitive Off–State Voltage(1) (T_J = –40 to 125°C, Sine Wave, 50 to 60 Hz, Gate Open)	MAC12D MAC12M MAC12N	V_{DRM}	 400 600 800	Volts
On–State RMS Current (Full Cycle Sine Wave, 60 Hz, T_C = 70°C)		$I_{T(RMS)}$	12	A
Peak Non–repetitive Surge Current (One Full Cycle, 60 Hz, T_J = 125°C)		I_{TSM}	100	A
Circuit Fusing Consideration (t = 8.3 ms)		I^2t	41	A^2sec
Peak Gate Power (Pulse Width ≤ 1.0 µs, T_C = 80°C)		P_{GM}	16	Watts
Average Gate Power (t = 8.3 ms, T_C = 80°C)		$P_{G(AV)}$	0.35	Watts
Operating Junction Temperature Range		T_J	–40 to +125	°C
Storage Temperature Range		T_{stg}	–40 to +150	°C

THERMAL CHARACTERISTICS

Thermal Resistance — Junction to Case — Junction to Ambient	$R_{\theta JC}$ $R_{\theta JA}$	2.2 62.5	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8″ from Case for 10 Seconds	T_L	260	°C

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS						
Peak Repetitive Blocking Current (V_D = Rated V_{DRM}, Gate Open)	T_J = 25°C T_J = 125°C	I_{DRM}	— —	— —	0.01 2.0	mA

(1) V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

This document contains information on a new product. Specifications and information herein are subject to change without notice.

Preferred devices are Motorola recommended choices for future use and best overall value.

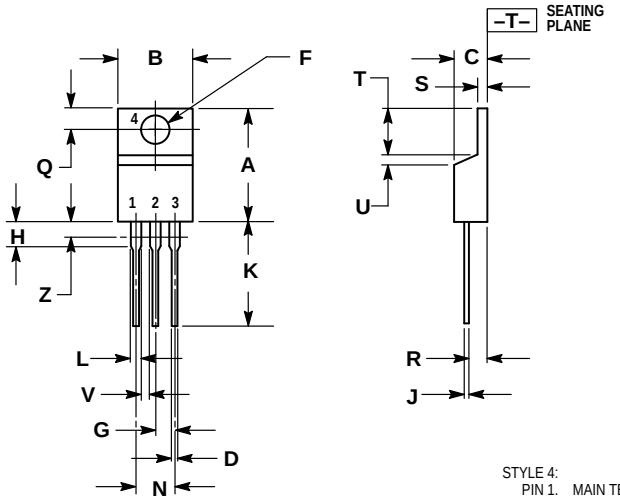
REV 2

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
ON CHARACTERISTICS					
Peak On–State Voltage* (I_{TM} = ±17 A)	V_{TM}	—	—	1.85	Volts
Continuous Gate Trigger Current (V_D = 12 V, R_L = 100 Ω) MT2(+), G(+) MT2(+), G(–) MT2(–), G(–)	I_{GT}	 5.0 5.0 5.0	 13 16 18	 35 35 35	mA
Hold Current (V_D = 12 V, Gate Open, Initiating Current = ±150 mA)	I_H	—	20	40	mA
Latch Current (V_D = 24 V, I_G = 35 mA) MT2(+), G(+); MT2(–), G(–) MT2(+), G(–)	I_L	 — —	 20 30	 50 80	mA
Gate Trigger Voltage (V_D = 12 V, R_L = 100 Ω) MT2(+), G(+) MT2(+), G(–) MT2(–), G(–)	V_{GT}	 0.5 0.5 0.5	 0.69 0.77 0.72	 1.5 1.5 1.5	Volts
DYNAMIC CHARACTERISTICS					
Rate of Change of Commutating Current* (V_D = 400 V, ITM = 4.4A, Commutating dv/dt = 18 V/μs, Gate Open, T_J = 125°C, f = 250 Hz, No Snubber)	(dv/dt)c	6.5	—	—	A/ms
Critical Rate of Rise of Off–State Voltage (V_D = Rated V_{DRM}, Exponential Waveform, Gate Open, T_J = 125°C)	dv/dt	250	—	—	V/μs

*Indicates Pulse Test: Pulse Width ≤2.0 ms, Duty Cycle ≤2%.

PACKAGE DIMENSIONS



STYLE 4:
PIN 1. MAIN TERMINAL 1
2. MAIN TERMINAL 2
3. GATE
4. MAIN TERMINAL 2

NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.570	0.620	14.48	15.75
B	0.380	0.405	9.66	10.28
C	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
H	0.110	0.155	2.80	3.93
J	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045	—	1.15	—
Z	—	0.080	—	2.04

CASE 221A-09
(TO–220AB)
ISSUE Z

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